

EPO-TEK® H70E-2 Technical Data Sheet For Reference Only Thermally Conductive, Electrically Insulating Epoxy

Date: September 2017 Recommended Cure: 150°C / 1 Hour Rev: VI No. of Components: Two Minimum Alternative Cure(s): Mix Ratio by Weight: May not achieve performance properties listed below 1:1 175°C / 1 Minute **Specific Gravity:** Part A: 1.50 Part B: 2.30 Pot Life: 150°C / 5 Minutes 2 Days Shelf Life- Bulk: One year at room temperature 120°C / 15 Minutes 80°C / 90 Minutes

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description</u>: EPO TEK® H70E-2 is a two component, thermally conductive electrically insulating epoxy designed for glob-top chip protection in TAB and COB die-attach technologies. It is used to prevent chips from being mechanically damaged during micro-package assembly and handling.

<u>Typical Properties:</u> Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results. Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:			
* Color (before cure):	Part	A: Black Pa	art B: Cream
* Consistency:	Smo	oth thixotropic	paste
* Viscosity (23°C) @ 20 rpm:	9	,000 - 15,000	cPs
Thixotropic Index:		1.7	
* Glass Transition Temp:		≥ 80	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)
Coefficient of Thermal Expansion (CTE):			
Belo	w Tg:	20	x 10 ⁻⁶ in/in°C
Abov	e Tg:	112	x 10 ⁻⁶ in/in°C
Shore D Hardness:		65	
Lap Shear @ 23°C:		> 2,000	psi
Die Shear @ 23°C:		≥ 5	Kg 1,778 psi
Degradation Temp:		447	C
Weight Loss:			
@ 2	00°C:	0.10	%
@ 2	50°C:	0.30	%
@ 3	00°C:	0.70	%
Suggested Operating Temperature:		< 300	°C (Intermittent)
Storage Modulus:		1,214,415	psi
Ion Content:	CI-:	267 ppm	
* Particle Size:		≤ 50	microns
ELECTRICAL AND THERMAL PROPERTIES:			
Thermal Conductivity:		1.0	W/mK
Volume Resistivity @ 23°C:		$\geq 8 \times 10^{12}$	Ohm-cm
Dielectric Constant (1KHz):		5.19	
Dissipation Factor (1KHz):		0.007	

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EPO-TEK[®] H70E-2 Advantages & Suggested Application Notes:

- The epoxy exhibits resistance against moisture, contamination and solvents which make it an ideal glob top. See Technical Paper #24 in our library for process flow in TAB packaging and reliability study – <u>http://www.epotek.com/technical-papers.asp</u>.
- A slightly thixotropic paste with excellent handling characteristics, pot life and short curing cycles. The rheology provides a dot-shape or dome configuration over wire-bonded die. Capable of glob-top DAM-and-FILL, or single-dot glob-top.
- Suitable for mass production as semiconductor encapsulant; low temp cure 80°C capable, controlled viscosity. Capable of many packages including TAB, COB, CSPs, BGAs, DIP and TO-cans.
- Excellent adhesion to PCB, ferrous and non-ferrous metals, glass, ceramic, epoxy package shells and semiconductor materials.
- Recommended for chip bonding, circuit repair, reinforce lead-frames, LSI chip packaging and good heat dissipation.